P70F7R5EN Power MOSFETs 75V, 70A, N-channel

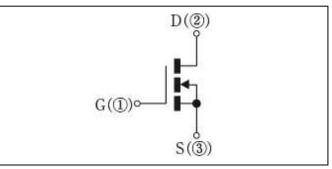
Feature

- N-channel
- Isolated Package
- Low Ron
- 10V Gate Drive
- Low Capacitance
- Pb free terminal
- RoHS:Yes

OUTLINE



Equivalent circuit



Absolute Maximum Ratings (unless otherwise specified : Tc=25°C)

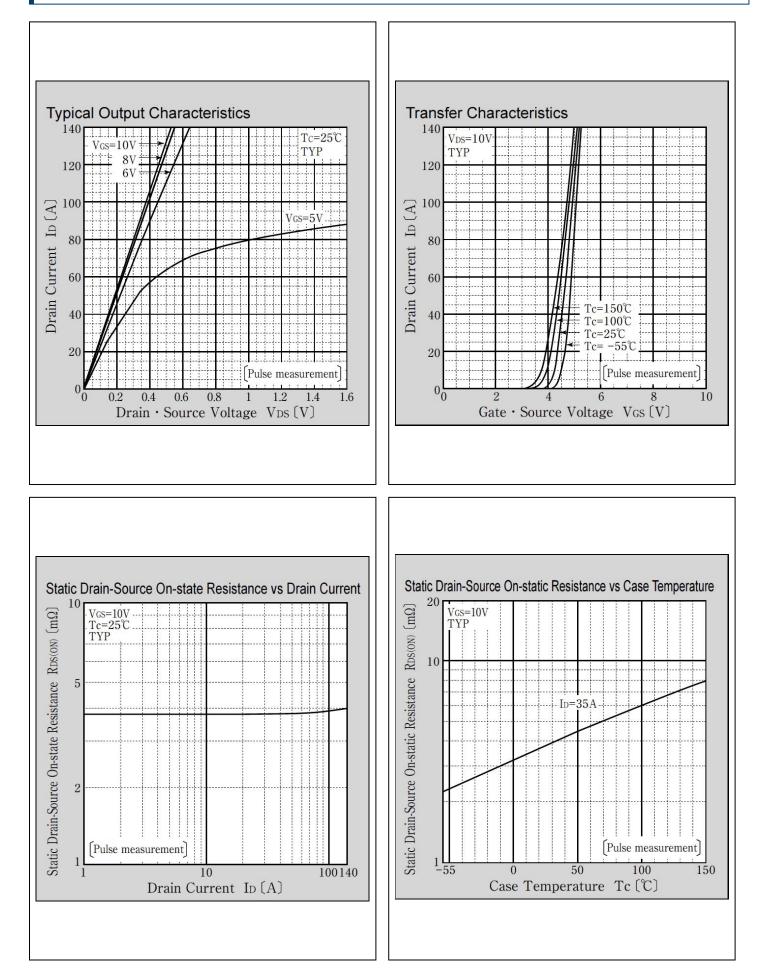
Item	Symbol	Conditions	Ratings	Unit
Storage temperature	Tstg		-55 to 150	°C
Channel tempertature	Tch		150	°C
Drain-source voltage	V _{DSS}		75	V
Gate-source voltage	V _{GSS}		±20	V
Continuous drain current(DC)	Ι _D		70	Α
Continuous drain current(Peak)	I _{DP}	Pulse width 10µs, duty=1/100	280	А
Continuous source current(DC)	ls		70	А
Total power dissipation	P _T		53	W
Single avalanche current	I _{AS}	Starting Tch=25°C Tch≦150°C	70	Α
Single avalanche energy	E _{AS}	Starting Tch=25°C Tch≦150°C	245	mJ
Dielectric strenght	Vdis	Terminals to case, AC1min	2	kV
Mounting torque	TOR	(Recommended torque:0.3N・m)	0.5	N∙m

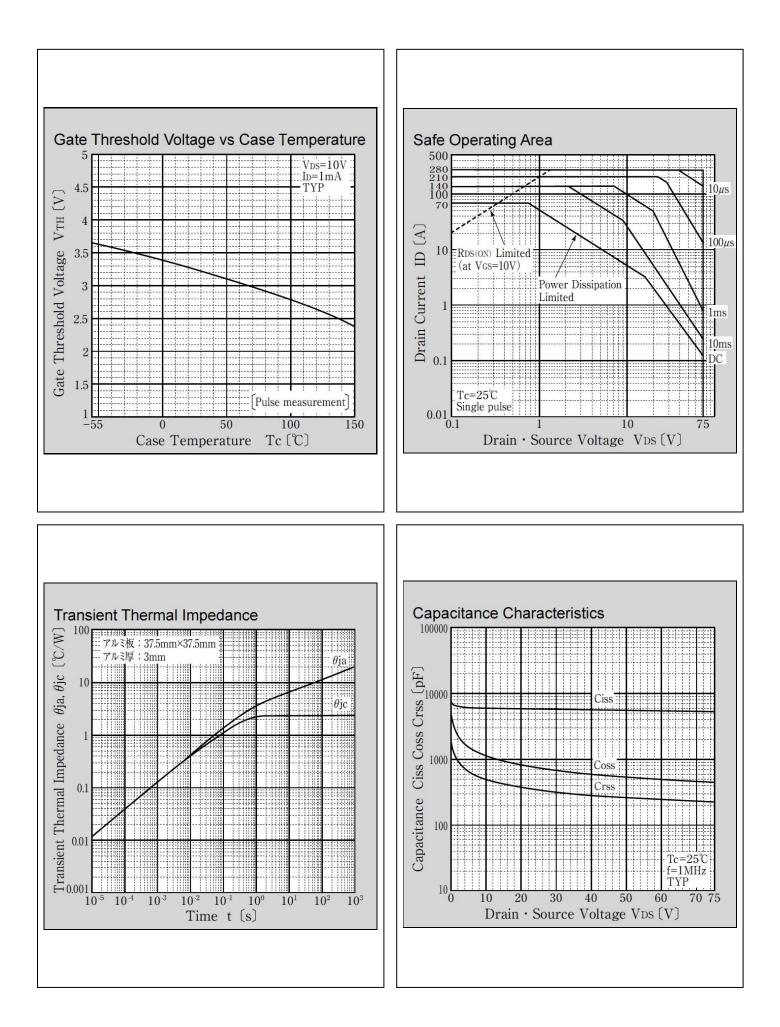
Electrical Characteristics (unless otherwise specified : Tc=25°C)

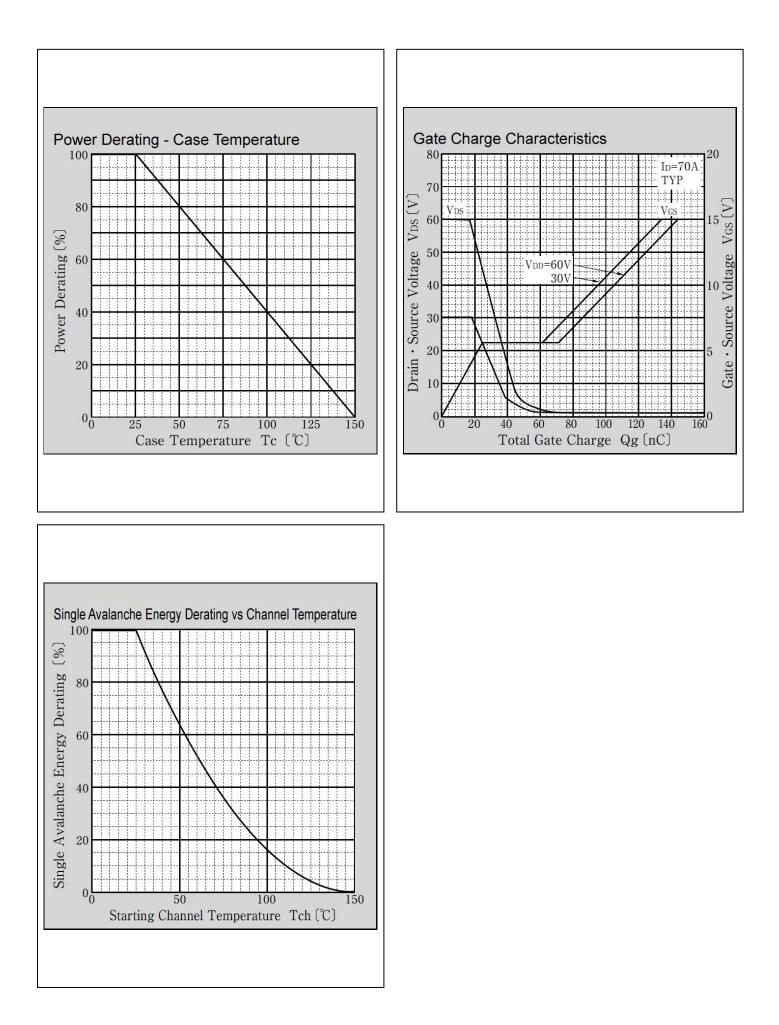
Item	Symbol	Conditions	Ratings			
			MIN	ТҮР	MAX	Unit
Drain-Source breakdown voltage	V _{(BR)DSS}	ID=1mA, VGS=0V	75			V
Zero gate voltage drain current	I _{DSS}	VDS=75V, VGS=0V			1	μA
Gate-source leakage current	I _{GSS}	VGS=±20V, VDS=0V			±0.1	μA
Forward transconductance	gfs	ID=35A, VDS=10V	25			S
Static drain-source on-state resistance	R _{DS(ON)}	ID=35A, VGS=10V		0.0038	0.0048	Ω
Gate threshold voltage	Vth	ID=1mA, VDS=10V	2	3	4	۷
Source-drain diode forward voltage	V _{SD}	IS=70A, VGS=0V			1.5	v
Thermal resistance	Rth(j-c)	Junction to case			2.35	°C/W
Total gate charge	Qg	VDD=60V, VGS=10V, ID=70A		105		nC
Gate to source charge	Qgs	VDD=60V, VGS=10V, ID=70A		27		nC
Gate to drain charge	Qgd	VDD=60V, VGS=10V, ID=70A		40		nC
Input capacitance	Ciss	VDS=25V, VGS=0V, f=1MHz		5720		pF
Reverce transfer capacitnce	Crss	VDS=25V, VGS=0V, f=1MHz		345		pF
Output capacitance	Coss	VDS=25V, VGS=0V, f=1MHz		745		pF
Turn-on delay time	td(on)	ID=35A, RL=1.2Ω, VDD=42V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		11		ns
Rise time	tr	ID=35A, RL=1.2Ω, VDD=42V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		43		ns
Turn-off delay time	td(off)	ID=35A, RL=1.2Ω, VDD=42V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		53		ns
Fall time	tf	ID=35A, RL=1.2Ω, VDD=42V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		56		ns
Diode reverse recovery time	trr	IF=70A, VGS=0V, di/dt=100A/µs		57		ns
Diode reverse recovery charge	Qrr	IF=70A, VGS=0V, di/dt=100A/µs		130		nC

※ ∶See the original Specifications

CHARACTERISTIC DIAGRAMS







unit:mm

 $\frac{4.5^{\pm 0.2}}{2.7^{\pm 0.2}}$

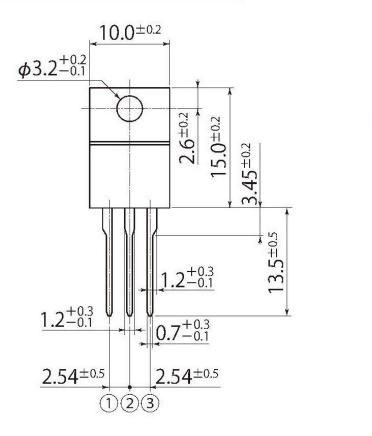
 $2.7^{\pm 0.2}$

0.5+0.3

6.7^{±0.2}

J8

JEDEC Code	-	
JEITA Code	SC-91	
House Name	FTO-220AG(3pin)	



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